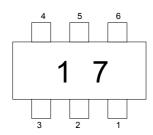
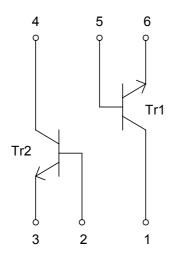
GENERAL PURPOSE DUAL TRANSISTOR

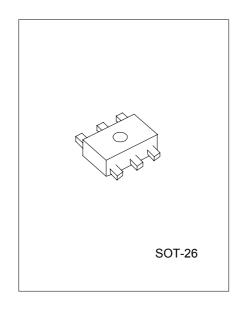
FEATURES

- *Two 2SD1484K chips in an SMT package.
- *Mounting possible with SMT3 automatic mounting machine.
- *Transistor elements are independent, eliminating interference.
- *High collector current. Ic=500mA
- *Mounting cost an area can be cut in half.

MARKING







PIN 1 : Collector (1) PIN 4: Collector (2)

PIN 2: Base (2) PIN 5: Base (1)

PIN 6: Emitter (1) PIN 3: Emitter (2)

The following characteristics apply to both Tr1 and Tr2.

ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	RATING	UNIT		
Collector-base voltage	Vсво	60	V		
Collector-emitter voltage	VCEO	50	V		
Emitter-base voltage	VEBO	5	V		
Collector current	lc	500	mA		
Collector dissipation	Pd	300 (TOTAL)	mW (note)		
Junction Temperature	Tj	150	°C		
Storage Temperature	Tstg	-55 ~ +150	°C		

Note: 200mW per element must not be exceeded.

ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	ВУсво	Ic=100μA	60			V
Collector-emitter breakdown voltage	BVCEO	Ic=1mA	50			V
Emitter-base breakdown voltage	ВУЕВО	IE=100μA	5			V
Collector cutoff current	Ісво	Vcb=30V			0.1	μΑ
Emitter cutoff current	IEBO	VEB=4V			0.1	μА
Collector-emitter saturation voltage	Vce(sat)	Ic=500mA, IB=50mA			0.6	V
DC current gain	hFE	VCE=3V,Ic=100mA (note)	120		390	
Transition frequency	fT	Vce=5V, I _E =-20mA, f=100MHz		250		MHz
Output capacitance	Cob	VCE=10V, I _E =0A, f=1MHz		7		pF

Note: Measured using pulse current.

CLASSIFICATION OF hFE

RANK	А	В		
RANGE	120-240	240-390		

ELECTRICAL CHARACTERISTIC CURVES

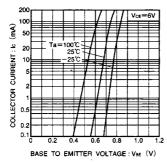


Fig.1 Grounded emitter propagation

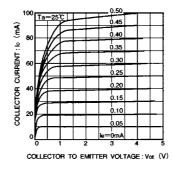


Fig.2 Grounded emitter output characteristics

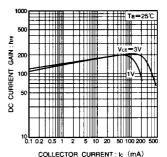


Fig.3 DC current gain vs. collector current (I)

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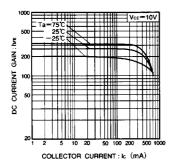
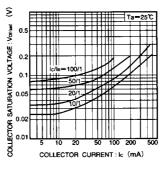


Fig.4 DC current gain vs. collector current (I)



Collector-emitter saturation voltage vs. collector current

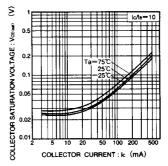


Fig.6 Collector-emitter saturation voltage vs. collector current

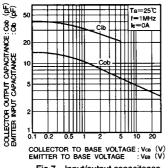


Fig.7 Input/output capacitance vs. voltage

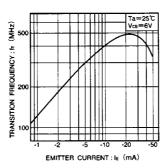


Fig.8 Gain bandwidth product vs. emitter current

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